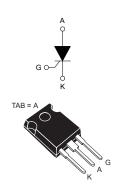


# 60 A 1200 V automotive grade thyristor (SCR)



TO-247 uninsulated

#### **Features**



High junction temperature: 150 °C
 AC off state voltage: +/- 1200 V

Nominal on-state RMS current: 60 A<sub>RMS</sub>

High noise immunity: 1000 V/µs
Max. gate triggering current: 50 mA

ECOPACK2 compliant component

#### **Applications**

- · On board, off board Automotive battery charger
- · AC DC voltage controlled rectifier
- Solar and wind renewable energy inverters / rectifiers
- · Solid state relays
- UPS: Bypass SSR; inrush current limiter ICL in AC DC rectifier

#### Description

The TN6050HP-12WY is an automotive grade SCR thyristor designed for applications such as automotive on board and stationary battery chargers.

This SCR thyristor, rated for a 60 A RMS power switching, offers superior performances in peak voltage robustness up to 1400 V and surge current handling up to 600 A sine wave pulse. Its key features allow the design of functions such as AC switch and AC-DC controlled rectifier-bridge.

The TN6050HP-12WY is available in TO-247 package, ideal for a maximum thermal performance.

# Product status TN6050HP-12WY

Product summary		
I <sub>T(RMS)</sub>	60 A	
$V_{DRM}/V_{RRM}$	1200 V	
V <sub>DSM</sub> /V <sub>RSM</sub>	1400 V	
I <sub>GT</sub>	50 mA	
T <sub>j</sub>	-40 to 150 °C	



### 1 Characteristics

Table 1. Absolute ratings (limiting values)

Symbol	Parameter	Value	Unit		
I <sub>T(RMS)</sub>	RMS on-state current (180 ° conduction angle)  T <sub>C</sub> = 134 °C				_
I <sub>T(AV)</sub>	Average on-state current (180 ° conduction angle)		1C = 134 C	38	Α
I	$t_{p} = 8.3 \text{ r}$		T. initial = 25 °C	660	_
I <sub>TSM</sub>	Non repetitive surge peak on-state current, V <sub>R</sub> = 0 V	t <sub>p</sub> = 10 ms	T <sub>j</sub> initial = 25 °C	600	A
l <sup>2</sup> t	I <sup>2</sup> t value for fusing	t <sub>p</sub> = 10 ms	T <sub>j</sub> = 25 °C	1800	A <sup>2</sup> s
dl/dt	$I_G = 2 \times I_{GT}$ , tr $\leq 100 \text{ ns}$			200	Λ/μο
ai/at	Critical rate of rise of on-state current $f = 50 \text{ Hz}$ $T_j = 150 \text{ °C}$		1j = 150 C	200	A/µs
$V_{DRM}$ / $V_{RRM}$	Repetitive off-state voltage	1200	V		
V <sub>DSM</sub> / V <sub>RSM</sub>	Non repetitive surge peak off-state voltage	t <sub>p</sub> = 10 ms	T <sub>j</sub> = 25 °C	1400	V
$V_{GM}$	Peak forward gate voltage	t <sub>p</sub> = 20 μs	T <sub>j</sub> = 150 °C	10	V
I <sub>GM</sub>	Peak forward gate current $t_p = 20 \mu s$ $T_j = 150  ^{\circ}C$				Α
$V_{RGM}$	Maximum peak reverse gate voltage	5	V		
P <sub>G(AV)</sub>	Average gate power dissipation	1	W		
T <sub>stg</sub>	Storage junction temperature range	-40 to +150	°C		
Tj	Operating junction temperature	-40 to +150	°C		

Table 2. Electrical characteristics ( $T_j$  = 25 °C unless otherwise specified)

Symbol	Test Conditions			Value	Unit	
lot			Min.	10	mA	
'G1	$V_{\text{GT}}$ $V_{\text{D}} = 12 \text{ V}, \text{ R}_{\text{L}} = 33 \Omega$		$V_D = 12 \text{ V}, R_L = 33 \Omega$	Max.	50	IIIA
V <sub>GT</sub>			Max.	1.3	V	
$V_{GD}$	$V_D$ = 800 V, $R_L$ = 3.3 k $\Omega$ $T_j$ = 150 °C		Min.	0.2	V	
I <sub>H</sub>	I <sub>T</sub> = 500 mA, gate open Max.		100	mA		
IL	$I_G = 1.2 \times I_{GT}$ Max.		125	mA		
dV/dt	$V_D$ = 800 V, gate open $T_j$ = 150 °C Min		Min.	1000	V/µs	

**Table 3. Timing Parameters** 

Symbol	Test Conditions			Value	Unit
t <sub>gt</sub>	$I_T$ = 120 A , $V_D$ = 800 V, $I_G$ = 100 mA, $dI_G/dt$ = 0.2 A/ $\mu$ s			1	μs
tq	$I_{TM}$ = 38 A, $V_D$ = 800 V, $dI_T/dt$ = 10 A/ $\mu$ s, $V_R$ = 75 V, $dV_D/dt$ = 20 V/ $\mu$ s, $t_p$ = 100 $\mu$ s	T <sub>j</sub> = 150 °C	Тур.	150	μs

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#### **Table 4. Static Characteristics**

Symbol	Test Conditions		Value	Unit	
V <sub>TM</sub>	I <sub>TM</sub> = 120 A, t <sub>P</sub> = 380 μs	T <sub>j</sub> = 25 °C	Max.	1.5	V
V <sub>TO</sub>	On-state threshold voltage	T <sub>j</sub> = 150 °C	Max.	0.83	V
R <sub>D</sub>	On-state dynamic resistance	T <sub>j</sub> = 150 °C	Max.	6	mΩ
		T <sub>j</sub> = 25 °C	Max.	5	μA
$I_{DRM}/I_{RRM}$ $V_D = V_{DR}$	$V_D = V_{DRM}, V_R = V_{RRM}$	T <sub>j</sub> = 125 °C	Max.	3	mA
		T <sub>j</sub> = 150 °C	Max.	7.5	mA
I <sub>DSM</sub> /I <sub>RSM</sub>	$V_D = V_{DSM}, V_R = V_{RSM}$	T <sub>j</sub> = 25 °C	Max.	10	μA

#### **Table 5. Thermal parameters**

Symbol	Parameter	Value	Unit	
R <sub>th(j-c)</sub>	Junction to case (DC)	Max.	0.3	°C/W
R <sub>th(j-a)</sub>	Junction to ambient	Тур.	50	C/VV

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#### 1.1 Characteristics curves

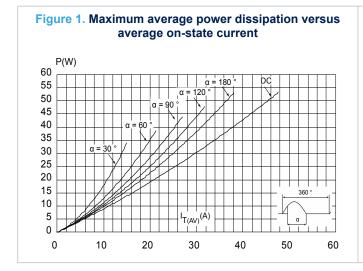


Figure 2. Average on-state current versus case temperature  $\mathsf{I}_{\mathsf{T}(\mathsf{AV})}(\mathsf{A})$ 70 60 50 α = 180 40 α = 120 30 α = 90 α = 60 20 α = 30 10 T<sub>c</sub>(°C) 0 0 25 50 100 125 150

Figure 3. On-state characteristics (maximum values)  $|T_{TM}(A)|$   $|T_$ 

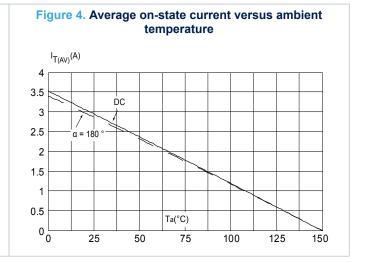
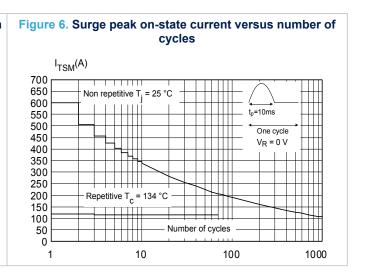


Figure 5. Relative variation of thermal impedance junction to case and junction to ambient versus pulse duration  $K = [Z_{th}/R_{th}]$ 1.0E-01

1.0E-02

1.0E-03 1.0E-02 1.0E-01 1.0E+00 1.0E+01 1.0E+02 1.0E+03



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Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse (tp < 10 ms)

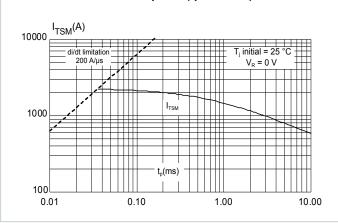


Figure 8. Relative variation of holding and latching current versus junction temperature (typical values)

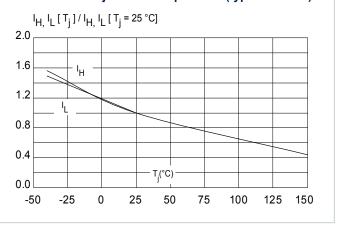


Figure 9. Relative variation of gate trigger current and gate voltage versus junction temperature (typical values)

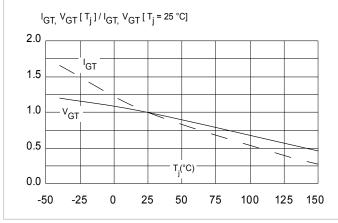


Figure 10. Relative variation of static dV/dt immunity versus junction temperature

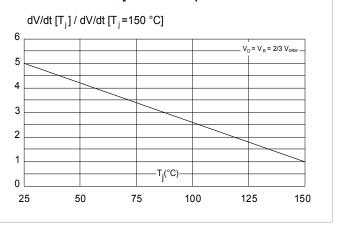
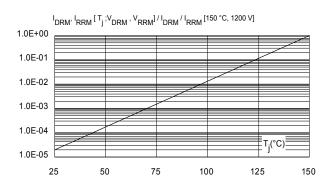


Figure 11. Relative variation of leakage current versus junction temperature for maximum of blocking voltage (typical values)



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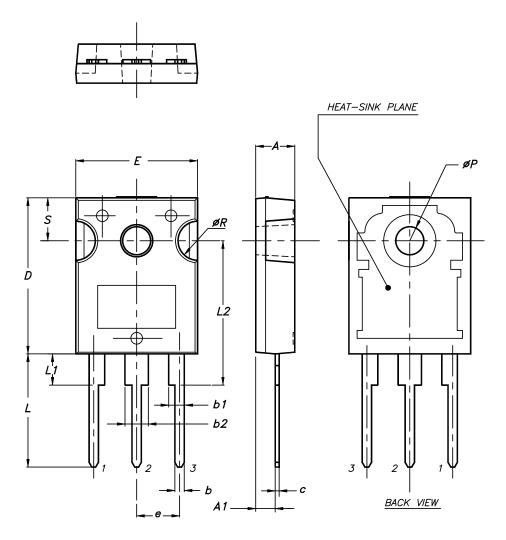
## Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

## 2.1 TO-247 package information

- Epoxy meets UL 94,V0
- Recommended torque value: 0.8 N·m
- Maximum torque value: 1 N·m

Figure 12. TO-247 package outline



0075325\_9

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Table 6. TO-247 package mechanical data

			Dime	nsions			
Dim.		Millimeters			Inches <sup>(1)</sup>		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	4.85		5.15	0.1909		0.2028	
A1	2.20		2.60	0.0866		0.1024	
b	1.0		1.40	0.0394		0.0551	
b1	2.0		2.40	0.0787		0.0945	
b2	3.0		3.40	0.1181		0.1339	
С	0.40		0.80	0.0157		0.0315	
D <sup>(2)</sup>	19.85		20.15	0.7815		0.7933	
E	15.45		15.75	0.6083		0.6201	
е	5.30	5.45	5.60	0.2087	0.2146	0.2205	
L	14.20		14.80	0.5591		0.5827	
L1	3.70		4.30	0.1457		0.1693	
L2		18.50			0.7283		
ØP <sup>(3)</sup>	3.55		3.65	0.1398		0.1437	
ØR	4.50		5.50	0.1772		0.2165	
S	5.30	5.50	5.70	0.2087	0.2165	0.2244	

<sup>1.</sup> Inch dimensions given only for reference

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<sup>2.</sup> Dimension D plus gate protrusion does not exceed 20.5 mm

<sup>3.</sup> Resin thickness around the mounting hole is not less than 0.9 mm





# 3 Ordering information

**Table 7. Ordering information** 

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN6050HP-12WY	TN6050HP12Y	TO-247	4.43 g	30	Tube

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## **Revision history**

**Table 8. Document revision history** 

Date	Revision	Changes
24-Apr-2020	1	Initial release.
04-Mar-2021	2	Updated Figure 3.
21-Sep-2021	3	Updated Features and Description on cover page.
	3	Updated Table 4 and Figure 6.

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